

1.Base 2.Collector 3.Emitter

## **NPN Epitaxial Silicon Transistor**

Absolute Maximum Ratings  $T_{C}=25^{\circ}C$  unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	160	V
V <sub>CEO</sub>	Collector-Emitter Voltage	140	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
lC	Collector Current (DC)	8	А
I <sub>CP</sub>	Collector Current (Pulse)	16	А
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	80	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

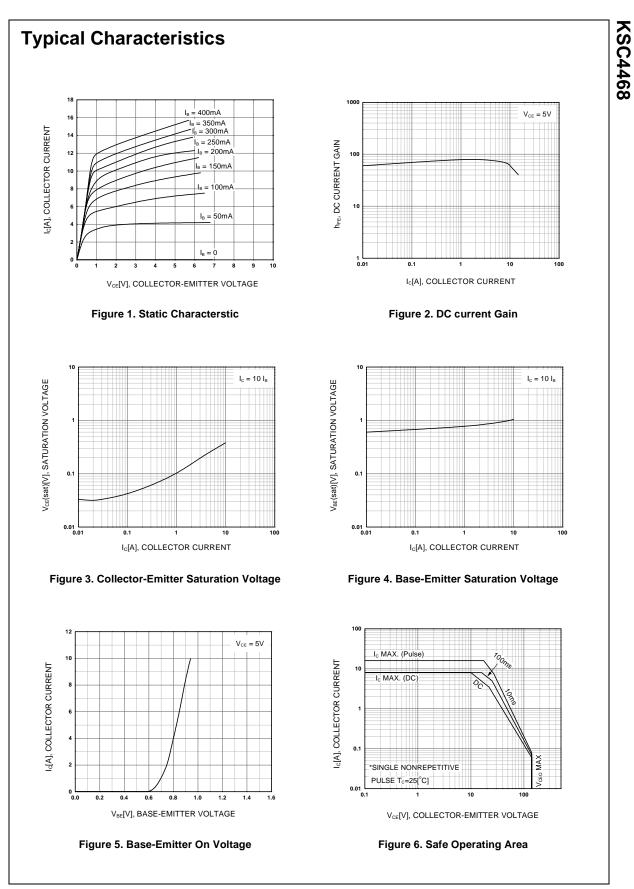
### Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =5mA, I <sub>E</sub> =0	160			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =10mA, R <sub>BE</sub> =∞	140			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =5mA, I <sub>C</sub> =0	6			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =80V, I <sub>E</sub> =0			0.1	mA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> =4V, I <sub>C</sub> =0			0.1	mA
h <sub>FE1</sub>	* DC Current Gain	V <sub>CE</sub> =5V, I <sub>C</sub> =1A	60		200	
h <sub>FE2</sub>		V <sub>CE</sub> =5V, I <sub>C</sub> =6A	20			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =5A, I <sub>B</sub> =0.5A			2.5	V
V <sub>BE</sub> (on)	Base-Emitter ON Voltage	V <sub>CE</sub> =5V, I <sub>C</sub> =1A			1.5	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =5V, I <sub>C</sub> =1A		30		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, f=1MHz		210		pF
t <sub>ON</sub>	Turn ON Time	V <sub>CC</sub> =20V,		0.26		μs
t <sub>F</sub>	Fall Time	I <sub>C</sub> =1A=10I <sub>B1</sub> =-10I <sub>B2</sub>		0.68		μs
t <sub>STG</sub>	Storage Time	$R_L=20\Omega$		6.68		μs

\* Pulse Test : PW=20µs

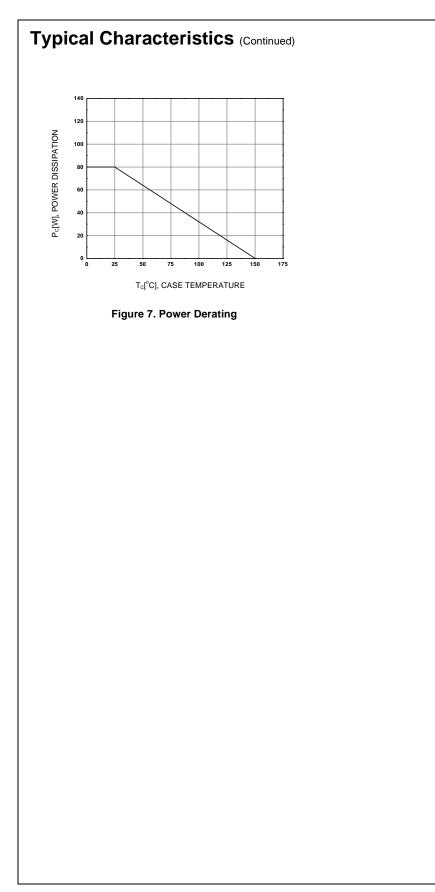
## h<sub>FE</sub> Classification

Classification	0	Y	
h <sub>FE1</sub>	60 ~ 120	100 ~ 200	

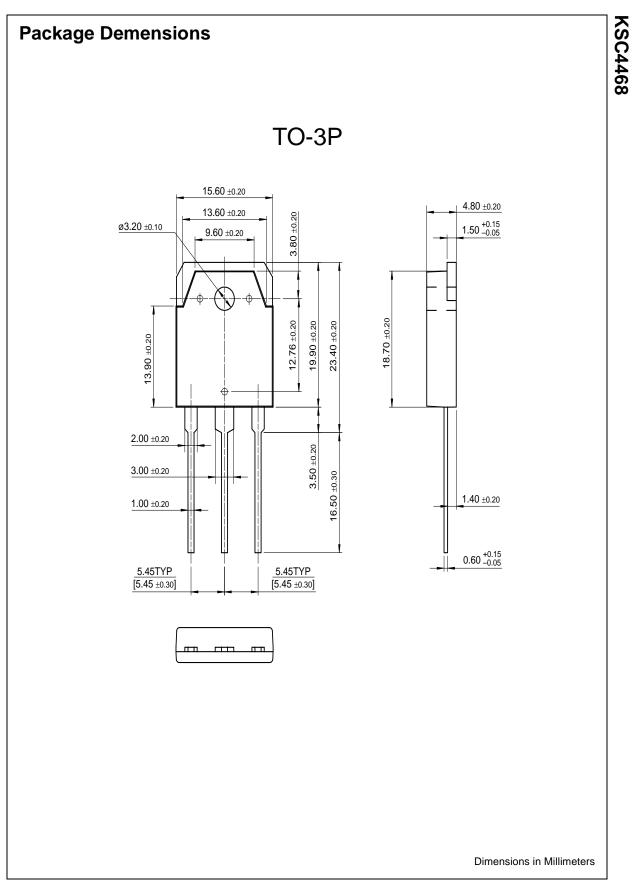


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Rev. B, Noverber 2000



# KSC4468



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